



Silicon NPN Phototransistor

Description

BPW96 is a high speed and high sensitive silicon NPN epitaxial planar phototransistor in a standard T-1 34 (\varnothing 5 mm) package. Due to its water-clear epoxy the device is sensitive to visible and near infrared radiation.

The viewing angle of \pm 20 $^{\circ}$ makes it insensible to ambient straylight.

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Features

- Fast response times
- · High photo sensitivity
- Standard T-1¾ (∅ 5 mm) clear plastic package
- Angle of half sensitivity $\varphi = \pm 20^{\circ}$
- Suitable for visible and near infrared radiation
- · Selected into sensitivity groups
- · Lead-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Applications

Detector in electronic control and drive circuits

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Collector Emitter Voltage		V _{CEO}	70	V
Emitter Collector Voltage		V _{ECO}	5	V
Collector current		I _C	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA
Total Power Dissipation	T _{amb} ≤ 47 °C	P _{tot}	150	mW
Junction Temperature		T _j	100	°C
Storage Temperature Range		T _{stg}	- 55 to + 100	°C
Soldering Temperature	t ≤ 3 s	T _{sd}	260	°C
Thermal Resistance Junction/ Ambient		R _{thJA}	350	K/W

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

and .						
Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Collector Emitter Breakdown Voltage	I _C = 1 mA	V _{(BR)CEO}	70			V
Collector-emitter dark current	V _{CE} = 20 V, E = 0	I _{CEO}		1	200	nA
Collector-emitter capacitance	$V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}, E = 0$	C _{CEO}		3		pF

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Optical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Angle of Half Sensitivity		φ		± 20		deg
Wavelength of Peak Sensitivity		λ_{p}		850		nm
Range of Spectral Bandwidth		λ _{0.5}		620 to 980		nm
Collector Emitter Saturation Voltage	$E_{e}=1 \text{ mW/cm}^{2}, \lambda=950 \text{ nm},$ $I_{C}=0.1 \text{ mA}$	V _{CEsat}			0.3	V
Turn-On Time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t _{on}		2.0		μs
Turn-Off Time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t _{off}		2.3		μs
Cut-Off Frequency	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	f _c		180		kHz

Type Dedicated Characteristics

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Collector Light Current	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $V_{CE} = 5 \text{ V}$	BPW96A	I _{ca}	1.5	2.5	4.5	mA
		BPW96B	I _{ca}	2.5	4.5	7.5	mA
		BPW96C	I _{ca}	4.5	8	15	mA

Typical Characteristics (Tamb = 25 °C unless otherwise specified)

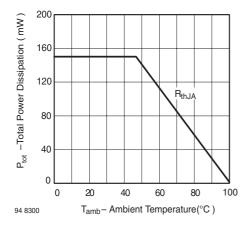


Figure 1. Total Power Dissipation vs. Ambient Temperature

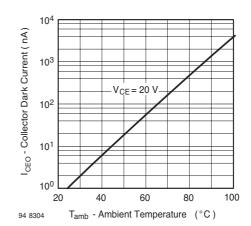


Figure 2. Collector Dark Current vs. Ambient Temperature



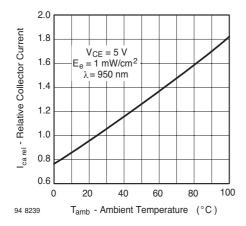


Figure 3. Relative Collector Current vs. Ambient Temperature

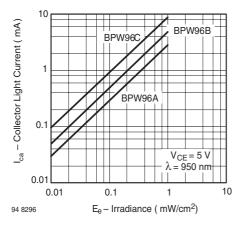


Figure 4. Collector Light Current vs. Irradiance

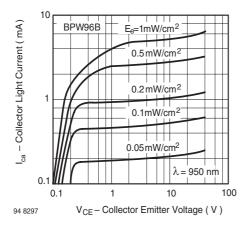


Figure 5. Collector Light Current vs. Collector Emitter Voltage

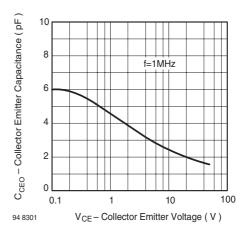


Figure 6. Collector Emitter Capacitance vs. Collector Emitter Voltage

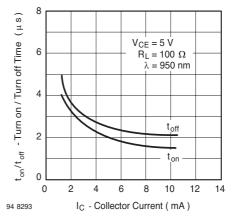


Figure 7. Turn On/Turn Off Time vs. Collector Current

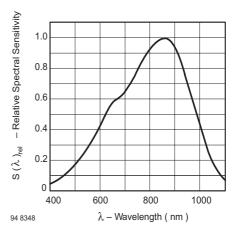
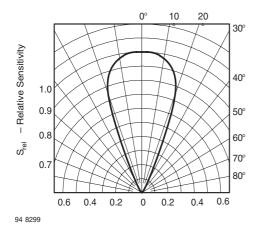


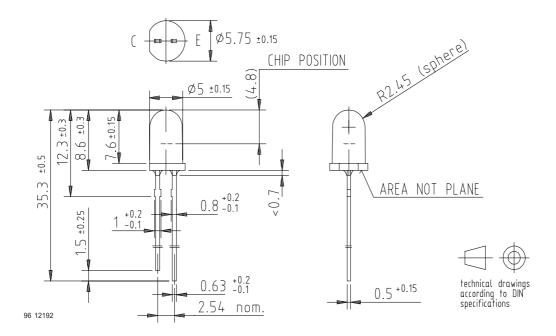
Figure 8. Relative Spectral Sensitivity vs. Wavelength



Figure 9. Relative Radiant Sensitivity vs. Angular Displacement



Package Dimensions in mm





Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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Document Number 81532 www.vishay.com Rev. 1.5, 08-Mar-05

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